TOSHIBA CMOS Linear Integrated Circuit Silicon Monolithic

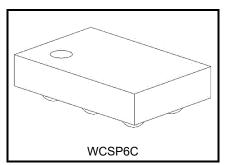
# **TCK111G, TCK112G**

3A, 8 m $\Omega$  Ultra Low On Resistance Load Switch IC with Reverse Current Blocking and Thermal Shutdown function

### 1. Description

The TCK111G and TCK112G are Load Switch ICs for power management with Reverse Current Blocking and Thermal Shutdown function featuring ultra low switch on resistance, high output current and wide input voltage operation from 1.1 to 5.5 V. Switch ON resistance is only 8.3 m $\Omega$  (typ.) at V<sub>IN</sub> = 5.0 V, -1.5 A load conditions and output current is available on 3.0 A. And these feature a slew rate control driver and output auto-discharge function.

These devices are available in 0.5 mm pitch ultra small package, WCSP6C (1.0 mm x 1.5 mm, t: 0.5 mm (typ.)). Thus they are ideal for portable applications that require high-density board assembly such as cellular phone.



Weight: 1.4 mg (typ.)

### 2. Features

• Low ON resistance:

 $R_{ON}$  = 8.3 m $\Omega$  (typ.) at V\_{IN} = 5.0 V, -1.5 A

- $R_{ON}$  = 8.4 m $\Omega$  (typ.) at V\_{IN} = 3.3 V, -1.5 A
- $R_{ON}$  = 8.4 m $\Omega$  (typ.) at  $V_{IN}$  = 1.8 V, -1.5 A
- $R_{ON}$  = 8.5 m $\Omega$  (typ.) at V\_{IN} = 1.1 V, -1.5 A
- Wide input voltage operation: V<sub>IN</sub> = 1.1 to 5.5 V
- Reverse current blocking
- Inrush current reducing circuit
- Thermal Shutdown function
- Output auto-discharge (TCK112G)
- Pull down connection between CONTROL and GND
- Ultra small package: WCSP6C (1.0 mm x 1.5 mm, t: 0.5 mm (typ.))

## Notice

This device is sensitive to electrostatic discharge. Please ensure equipment and tools are adequately earthed when handling.

## 3. Absolute Maximum Ratings (Ta = 25°C) (Note)

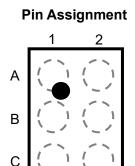
| Characteristics             | Symbol           |            | Unit         |    |  |  |
|-----------------------------|------------------|------------|--------------|----|--|--|
| Input voltage               | VIN              |            | -0.3 to 6.0  |    |  |  |
| Control voltage             | V <sub>CT</sub>  |            | -0.3 to 6.0  |    |  |  |
| Output voltage              | Vout             |            | -0.3 to 6.0  |    |  |  |
| Output current              | Ιουτ             | DC         | 3.0          | А  |  |  |
|                             |                  | Pulse      | 4.0 (Note 1) | А  |  |  |
| Power dissipation           | PD               |            | 1.2 (Note 2) |    |  |  |
| Operating temperature range | Topr             | -40 to 85  |              | °C |  |  |
| Junction temperature        | Tj               | 150        |              |    |  |  |
| Storage temperature         | T <sub>stg</sub> | -55 to 150 |              |    |  |  |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

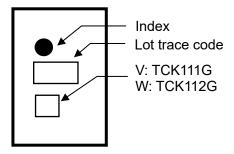
Note1: 100 µs pulse, 2% duty cycle

Note2: Rating at mounting on a board (Board material: Glass epoxy (FR4) Board dimension: 25.4 mm x 25.4 mm (both sides of board), t=1.6 mm, Cu pad area: 645 mm<sup>2</sup>)

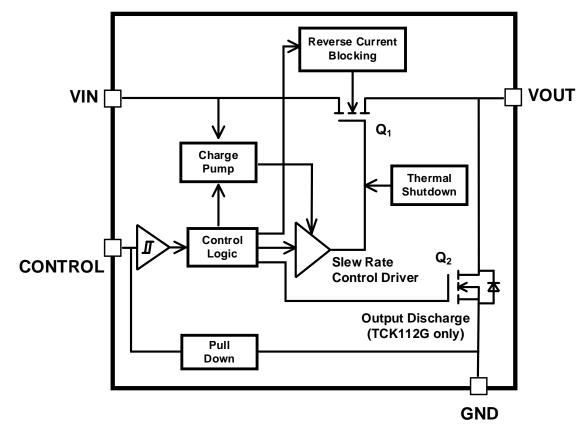
## 4. Pin Assignment, Top Marking (Top view)



A1: VOUT B1: VOUT C1: GND A2: VIN B2: VIN C2: CONTROL Top Marking



## 5. Block Diagram



### 5.1. Function table

|             | Function                 |                  |                       |                        |  |  |  |
|-------------|--------------------------|------------------|-----------------------|------------------------|--|--|--|
| Part number | Reverse current blocking | Thermal shutdown | Output auto-discharge | Control pin connection |  |  |  |
| TCK111G     | Built in                 | Built in         | N/A                   | Pull down              |  |  |  |
| TCK112G     | Built in                 | Built in         | Built in              | Pull down              |  |  |  |

### 5.2. Operation Logic table

#### 1.1 V ≤ V<sub>IN</sub> ≤ 5.5 V (Ta = -40 to 85°C)

|                   |                          | TCK111G | TCK112G |
|-------------------|--------------------------|---------|---------|
|                   | Output Q <sub>1</sub>    | ON      | ON      |
| Control           | Discharge Q <sub>2</sub> | —       | OFF     |
| "High"            | Reverse current block    | Active  | Active  |
|                   | Output Q <sub>1</sub>    | OFF     | OFF     |
| Control           | Discharge Q <sub>2</sub> | —       | ON      |
| "Low"             | Reverse current block    | Active  | Active  |
| Ocentral          | Output Q <sub>1</sub>    | OFF     | OFF     |
| Control<br>"OPEN" | Discharge Q <sub>2</sub> | —       | ON      |
|                   | Reverse current block    | Active  | Active  |

## 6. Electrical Characteristics

## 6.1. DC Characteristics (Ta = -40 to 85°C)

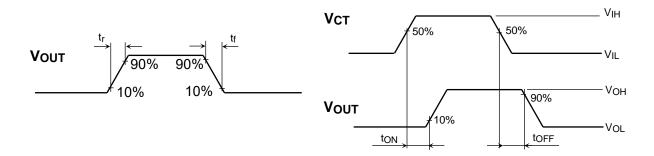
|  | Symbol              | Test Condition  |   | Ta = 25°C |      |     | Ta = −40 to 85°C |     |      |
|--|---------------------|---|---|-----------|------|-----|------------------|-----|------|
| Characteristics                            |                     |   |   | Min       | Тур. | Max | Min              | Мах | Unit |
| Input voltage                              | V <sub>IN</sub>     | _   |   | 1.1       | _    | 5.5 | 1.1              | 5.5 | V    |
| CONTROL High-level input voltage           | V <sub>IH</sub>     | 1.2V < V <sub>IN</sub> ≤ 5.5 V  |   | 1.0       |      |     | 1.0              | —   | v    |
|  |                     | 1.1V ≤ V <sub>IN</sub> ≤ 1.2 V  |   | 0.9       | _    | _   | 0.9              | _   |      |
| CONTROL Low-level input voltage            | VIL                 | V <sub>IN</sub> = 1.1 to 5.5 V  |   |           |      | 0.4 | —                | 0.4 | V    |
| Quiescent current (ON state)               | IQ                  | I <sub>OUT</sub> = 0 mA   | $V_{\rm IN} = V_{\rm CT} = 1.1 \ V$       | _         | 55   | _   | _                | —   | μA   |
|  |                     |   | V <sub>IN</sub> = V <sub>CT</sub> = 1.8 V |           | 50   |     | _                | _   | μA   |
|  |                     |   | $V_{\rm IN} = V_{\rm CT} = 3.3 \text{ V}$ | _         | 48   | _   | _                | —   | μA   |
|  |                     |   | $V_{\rm IN}=V_{\rm CT}=5.0~V$             | _         | 69   | —   | _                | 106 | μA   |
| Standby current (OFF state)                | I <sub>Q(OFF)</sub> | $V_{\text{IN}} = 5.5 \text{ V}, V_{\text{CT}} = 0 \text{ V},$<br>VOUT = OPEN (Note 3) |   | _         | 0.5  | _   | _                | 1.4 | μA   |
| Reverse blocking current                   | I <sub>RB</sub>     | $V_{OUT} = 5.0 \text{ V}, V_{IN} = 0 \text{ V}, V_{CT} = 0 \text{ V}$                 |   | _         | 0.6  |     | —                | 10  | μA   |
| Reverse blocking voltage threshold         | V <sub>RB</sub>     | $V_{OUT} - V_{IN}$  |   | _         | 40   | _   | —                | —   | mV   |
| Reverse blocking release voltage threshold | V <sub>RBR</sub>    | V <sub>OUT</sub> – V <sub>IN</sub>  |   | _         | -30  | _   | _                | _   | mV   |
| On resistance                              | R <sub>on</sub>     | I <sub>OUT</sub> = -1.5 A   | V <sub>IN</sub> = 5.0 V                   | _         | 8.3  | _   | —                | 15  | mΩ   |
|  |                     |   | V <sub>IN</sub> = 3.3 V                   | _         | 8.4  | _   | —                | _   |      |
|  |                     |   | V <sub>IN</sub> = 1.8 V                   | _         | 8.4  | _   | —                | _   |      |
|  |                     |   | V <sub>IN</sub> = 1.1 V                   | _         | 8.5  | _   | —                | 15  |      |
| Output discharge on resistance             | R <sub>SD</sub>     | (TCK112G only)  |   | _         | 380  | _   | —                | —   | Ω    |

Note 3 : Except OFF-state switch current (I<sub>SD(OFF)</sub> : V<sub>IN</sub> = 5.5 V, V<sub>CT</sub> = 0 V, V<sub>OUT</sub> = GND ).

### 6.2. AC Characteristics (Ta = 25°C)

| Characteristics            | Symbol           | Test Condition (Figure 1)  | Min | Тур. | Max | Unit |
|----------------------------|------------------|--|-----|------|-----|------|
| V <sub>OUT</sub> rise time | tr               | $V_{\text{IN}}$ = 5.0 V , $R_{\text{L}}$ = 2.5 $\Omega$ , $C_{\text{L}}$ = 1.0 $\mu\text{F}$ | _   | 0.5  | _   | ms   |
| V <sub>out</sub> fall time | t <sub>f</sub>   | $V_{\text{IN}}$ = 5.0 V , $R_{\text{L}}$ = 2.5 $\Omega$ , $C_{\text{L}}$ = 1.0 $\mu\text{F}$ | _   | 5    | _   | μs   |
| Turn on delay              | t <sub>ON</sub>  | $V_{\text{IN}}$ = 5.0 V , $R_{\text{L}}$ = 2.5 $\Omega$ , $C_{\text{L}}$ = 1.0 $\mu\text{F}$ | _   | 0.2  | —   | ms   |
| Turn off delay             | t <sub>OFF</sub> | $V_{\text{IN}}$ = 5.0 V , $R_{\text{L}}$ = 2.5 $\Omega$ , $C_{\text{L}}$ = 1.0 $\mu\text{F}$ | _   | 4    | —   | μs   |

#### AC Waveform

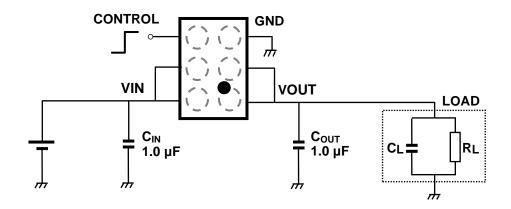




### 7. Application Note

### 7.1. Application circuit example (top view)

The below figure shows the example of configuration for TCK111G and TCK112G.



#### 1) Input and Output capacitor

An input capacitor ( $C_{IN}$ ) and an output capacitor ( $C_{OUT}$ ) are necessary for the stable operation of TCK111G and TCK112G. They are effective to reduce voltage overshoot or undershoot due to sharp changes in output current and also for improved stability of the power supply. When used, place  $C_{IN}$  and  $C_{OUT}$  more than 1.0µF as close to VIN pin to improve stability of the power supply.

#### 2) Control pin

Control pins for TCK111G and TCK112G are both Active High, which control both the pass-through N-ch MOSFET and the discharge N-ch MOSFET (only for TCK112G), operated by the control voltage. Each control pin is equipped with Schmitt trigger. When the control voltage level is High, Output N-ch MOSFET is ON state and discharge N-ch MOSFET is OFF state. When control voltage level is Low, and the state of the MOSFETs is reversed. Also, pull down resistance equivalent to a few M $\Omega$  is connected between CONTROL and GND, thus the load switch IC is in OFF state even when CONTROL pin is OPEN. In addition, CONTROL pin has a tolerant function such that it can be used even if the control voltage is higher than the input voltage.

#### 7.2. Reverse current blocking

Reverse current blocking function is designed in these products. This function is active regardless output N-ch MOSFET ON/OFF state in condition that VIN is supplied.

However, these do not assure for the suppression of uprising device operation. In use of these products, please read through and understand dissipation idea for absolute maximum ratings from the above mention or our 'Semiconductor Reliability Handbook'. Then use these products under absolute maximum ratings in any condition. Furthermore, Toshiba recommends inserting failsafe system into the design.

#### 7.3. Thermal shutdown function

Thermal shutdown function is designed in these products, but it does not assure for the suppression of uprising device operation. In use of these products, please read through and understand dissipation idea for absolute maximum ratings from the above mention or our 'Semiconductor Reliability Handbook'. Then use these products under absolute maximum ratings in any condition. Furthermore, Toshiba recommends inserting failsafe system into the design.

#### 7.4. Power Dissipation

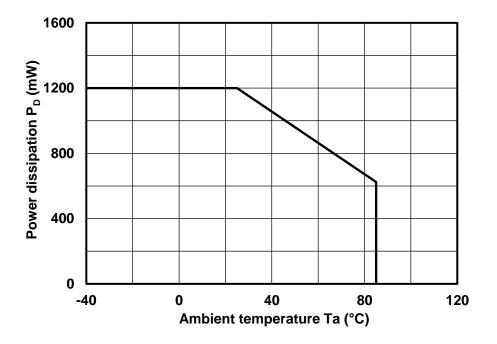
Board-mounted power dissipation ratings for TCK111G and TCK112G are available in the Absolute Maximum Ratings table.

Power dissipation is measured on the board condition shown below.

#### [The Board Condition]

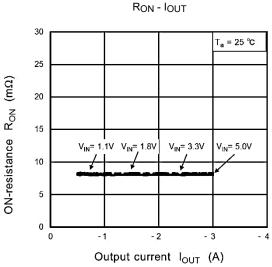
Board material: Glass epoxy (FR4)

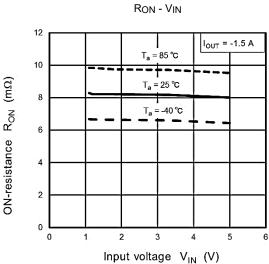
Board dimension: 25.4 mm x 25.4 mm (both sides of board), t = 1.6 mm, Cu pad area:  $645 \text{ mm}^2$ 



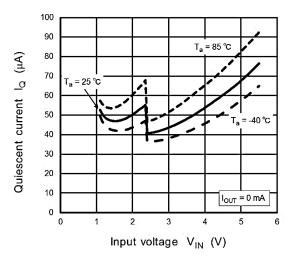
Please allow sufficient margin when designing a board pattern to fit the expected power dissipation. Also take into consideration the ambient temperature, input voltage, output current etc. and applying the appropriate derating for allowable power dissipation during operation.

## 8. Representative Typical Characteristics (Note)

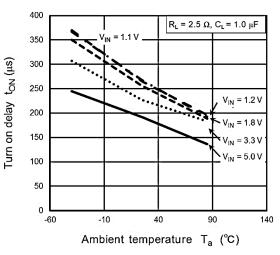


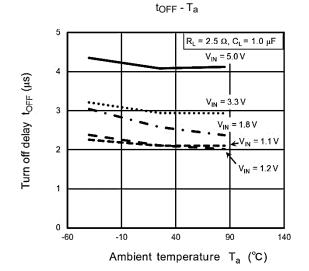




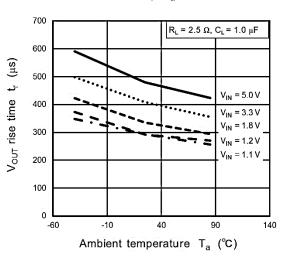






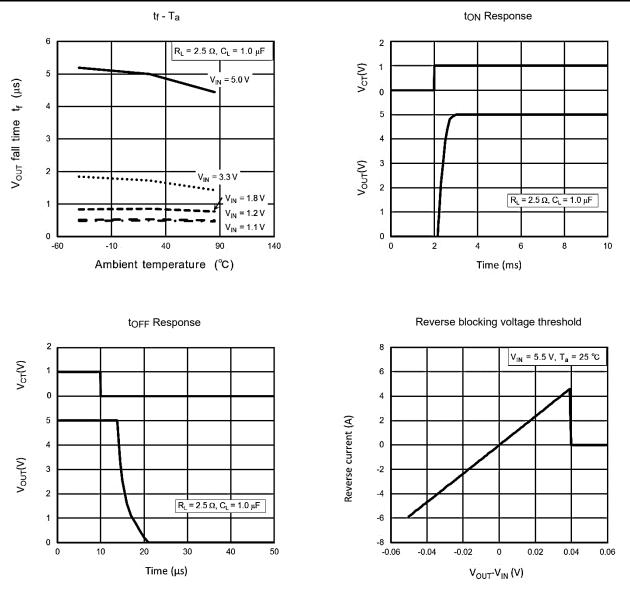


tr - Ta



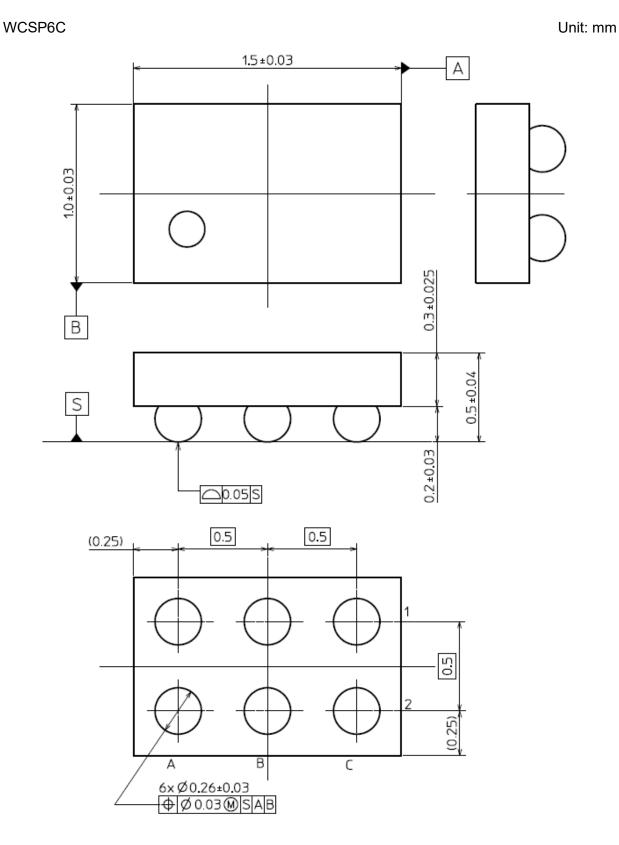
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## TCK111G,TCK112G



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

## 9. Package Information

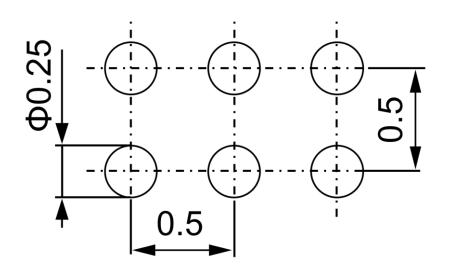


Weight: 1.4 mg (typ.)



## **10. Land pattern Dimensions (for reference only)**

Unit: mm



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